Ordering number : ENN6621



SI PO1SP

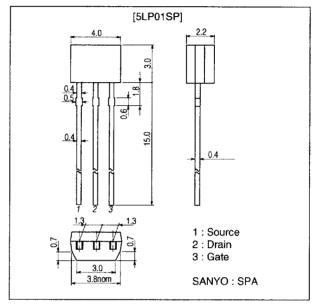
Ultrahigh-Speed Switching Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 2.5V drive.

Package Dimensions

unit : mm 2180



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-50	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	ID.		-0.07	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-0.28	Α
Allowable Power Dissipation	PD		0.25	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	İ	Ratings		
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0	-50			V
Zero-Gate Voltage Drain Current	IDSS	Vps=-50V, Vgs=0			10	μА
Gate-to-Sourse Leakage Current	GSS	V _{GS} =±8V, V _{DS} =0			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =-10V, I _D =-100μA	-0.4		-1.4	V

Marking: XB

Continued on next page.

- Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.
- SANYO assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO products described or contained herein.

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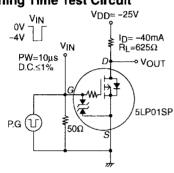
5LP01SP

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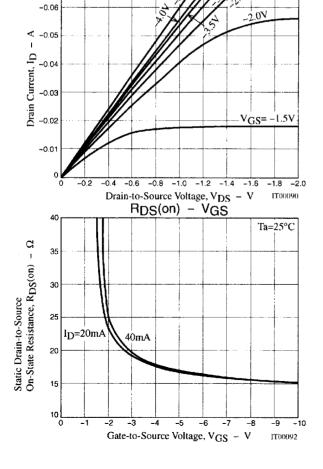
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Forward Transfer Admittance	yfs	VDS=-10V, ID=-40mA	70	100		mS
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-40mA, VGS=-4V		18	23	Ω
	RDS(on)2	ID=-20mA, VGS=-2.5V		20	28	Ω
	R _{DS} (on)3	ID=-5mA, VGS=-1.5V		30	60	Ω
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		7.4		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		4.2		pF
Reverse Transfer Capacitance	Crss	VDS=-10V, f=1MHz		1.3		ρF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		20		ns
Rise Time	tr	See specified Test Circuit		35		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		160		ns
Fall Time	tf	See specified Test Circuit		150		ns
Total Gate Charge	Qg	VDS=-10V, VGS=-10V, ID=-70mA		1.40		nC
Gate-to-Source Charge	Qgs	VDS=-10V, VGS=-10V, ID=-70mA		0.16		nC
Gate-to-Drain "Miller" Charge	Qgd	VDS=-10V, VGS=-10V, ID=-70mA		0.23		nC
Diode Forward Voltage	V _{SD}	Is=-70mA, VGS=0		0.85	1.2	٧

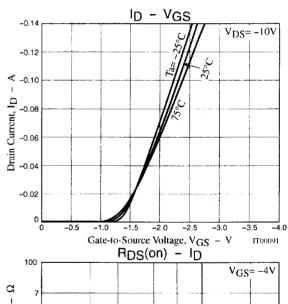
Switching Time Test Circuit

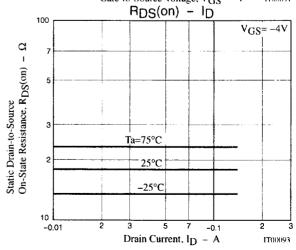
-0.07



- VDS

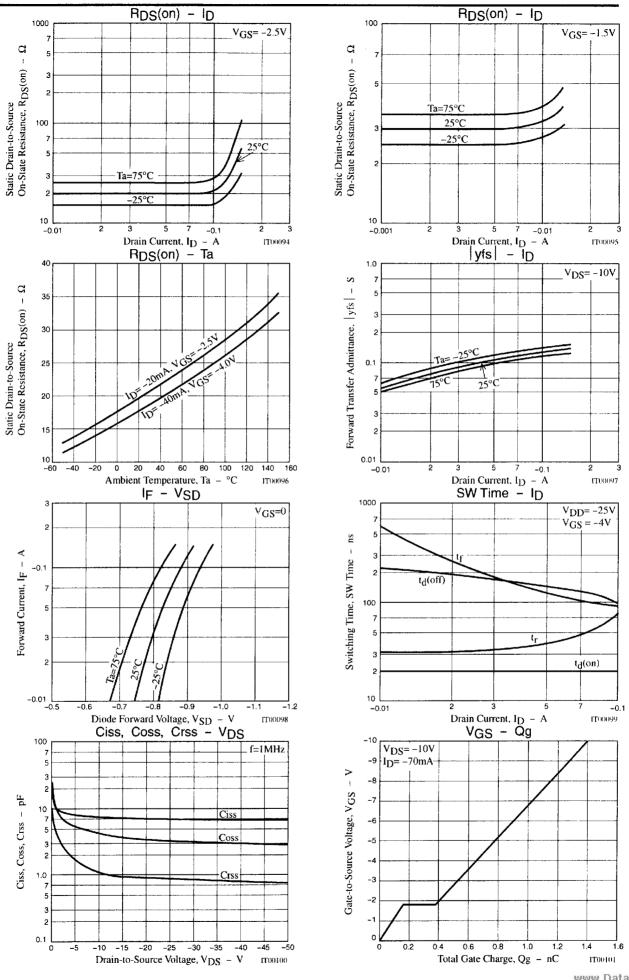






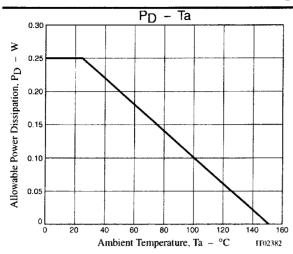
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5LP01SP



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5LP01SP



Note on usage: Since the 5LP01SP is designed for high-speed switching applications, please avoid using this device in the vicinity of highly charged objects.

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